INTEGRATED CIRCUITS

DATA SHEET

GTL2005 Quad GTL/GTL+ to LVTTL/TTL bidirectional non-latched translator

Product specification Supersedes data of 1999 Sep 17





Quad GTL/GTL+ to LVTTL/TTL bidirectional non-latched translator

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FEATURES

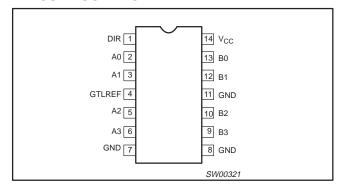
- Operates as a quad GTL/GTL+ sampling receiver or as a LVTTL/TTL to GTL/GTL+ driver
- Quad bidirectional bus interface
- Live insertion/extraction permitted
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114, and 1000 V CDM per JESD22-CC101

DESCRIPTION

The GTL2005 is a quad translating transceiver designed for 3.3 V system interface with a GTL/GTL+ bus.

The direction pin allows the part to function as either a GTL to TTL sampling receiver or as a TTL to GTL interface.

PIN CONFIGURATION



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPI B to A	UNIT	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	$C_L = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	2.1 1.9	4.1 4.3	ns
C _{IN}	Input capacitance DIR	$V_I = 0 \text{ V or } V_{CC}$	3.0	3.0	pF
C _{I/O}	I/O pin capacitance	Outputs disabled; V _{I/O} = 0 V or 3.0 V	7.8	4.5	pF

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
14-Pin Plastic TSSOP Type II	-40°C to +85°C	GTL2005 PW DH	SOT402-1

PIN DESCRIPTION

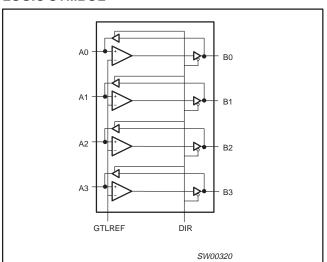
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 5, 6	A0 – A3	Data inputs/outputs (A side, GTL)
13, 12, 10, 9	B0 – B3	Data inputs/outputs (B side, TTL)
4	GTLREF	GTL reference voltage
7, 8, 11	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

FUNCTION TABLE

INPUT	INPUT/C	DUTPUT
DIR	В	Α
Н	Inputs	Bn = An
L	An = Bn	Inputs

H = HIGH voltage level L = LOW voltage level

LOGIC SYMBOL



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ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum System (IEC 134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
Vı	DC input voltage ³	A port	-0.5 to +7.0	V
V	DC input voltage	B port	-0.5 to +4.6	V
I _{OK}	DC output diode current	V _O < 0	- 50	mA
V-	DC output voltage ³	Output in Off or High state; A port	-0.5 to +7.0	V
Vo	DC dulput voltage-	Output in Off or High state; B port	-0.5 to +4.6	V
1	Current into any output in the LOW state	A port	128	mA
l _{OL}	Current into any output in the LOW state	B port	80	mA
I _{OH}	Current into any output in the HIGH state	A port	-64	mA
T _{stg}	Storage temperature range		-60 to +150	°C

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction
- temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

 3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS¹

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage		0		3.6	V
	Towns in actions well-to are	GTL	1.14	1.2	1.26	V
V _{TT}	Termination voltage	GTL+	1.35	1.5	1.65	l ^v
.,	Cumply yeltogo	GTL	0.74	0.8	0.87	V
V_{REF}	Supply voltage	GTL+	0.87	1.0	1.10	l ^v
\/	Input voltage	A port	0	0	V _{TT}	V
VI	input voitage	Except A port	0		5.5]
V	LUCI Lloyal innut valtage	A port	V _{REF} + 50 mV			V
V _{IH}	HIGH-level input voltage	Except A port	2			ľ
\/	LOW level input voltage	A port			V _{REF} – 50 mV	V
V _{IL}	LOW-level input voltage	Except A port			0.8	ľ
I _{OH}	HIGH-level output current	B port			-12	mA
,	LOW/ lovel output ourrent	A port			40	mA
l _{OL}	LOW-level output current	B port			12	mA
T _{amb}	Operating free-air temperature range		-40		85	°C

NOTE:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

				LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40	5°C	UNIT		
			MIN TYP ¹ MA		MAX		
\ <u>'</u>	D north	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}; I_{OH} = -100 \mu\text{A}$	V _{CC} -0.2			V	
V _{OH}	B port	$V_{CC} = 3.0 \text{ V}; I_{OH} = -12 \text{ mA}$	2.0			V	
	A port	$V_{CC} = 3.0 \text{ V}; I_{OL} = 40 \text{ mA}$			0.4	V	
V _{OL}	B port	$V_{CC} = 3.0 \text{ V}_{;} I_{OL} = 12 \text{ mA}$			0.8	V	
	Control inputs	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND}$			± 1		
	A port	$V_{CC} = 3.6 \text{ V}; V_I = V_{TT} \text{ or GND}$			± 1	1	
l _l		V _{CC} = 0 or 3.6 V; V _I = 5.5			10	μΑ	
	B port	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC}$			± 1	1	
		V _{CC} = 3.6 V; V _I = 0 V			- 5	1	
I _{OFF}	A port	$V_{CC} = 0 \text{ V; V}_{I} \text{ or V}_{O} = 0 \text{ to } 4.5 \text{ V}$			± 100	μΑ	
I _{EX}	B port	V _O = 5.5 V; V _{CC} = 3.0 V		50	125	μА	
Icc	A or B port	$V_{CC} = 3.6 \text{ V; } V_{I} = V_{CC} \text{ or GND; } I_{O} = 0$			3	mA	
∆l _{CC} ³	B port or control inputs	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} - 0.6 \text{ V}$			500	μА	
C _I	Control inputs	V _I = 3.0 V or 0		3		pF	
	B port	V _O = 3.0 V or 0		7.8			
C _{IO}	A port	$V_O = V_{TT}$ or 0		4.5		pF	

NOTES:

- All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25°C.
 The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC or GND}.

AC CHARACTERISTICS (3.3 V \pm 0.3 V RANGE)

			L	IMITS (GTL)	LI	MITS (GTL-	+)	
SYMBOL	PARAMETER	WAVEFORM	Vcc	= 3.3 V \pm 0/REF = 0.8 V	.3 V	Vcc	= 3.3 V \pm 0 / _{REF} = 1.0 V	.3 V	UNIT
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	1
t _{PLH} t _{PHL}	Bn to An	1		2.1 1.9	2.3 2.6		2.1 1.9	2.3 2.6	ns
t _{PLH} t _{PHL}	An to Bn	2		4.1 4.4	5.4 5.4		4.2 3.8	5.3 4.8	ns

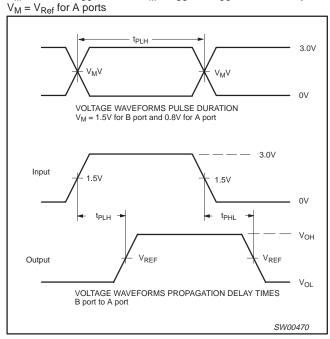
^{1.} All typical values are at V_{CC} = 3.3 V and T_{amb} = 25°C.

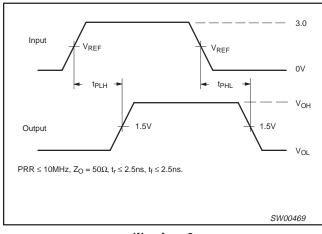
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AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \ge 3.0$ V, V_M = $V_{CC}/2$ at $V_{CC} \le 2.7$ V for B ports and control pins





Waveform 2.

Waveform 1.

TEST CIRCUIT

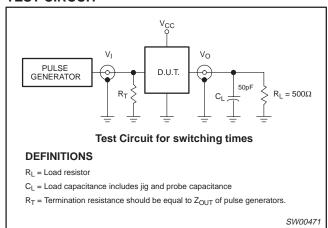


Figure 1. Load circuitry for switching times

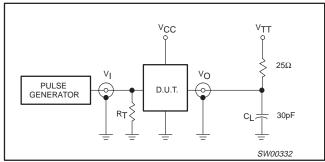


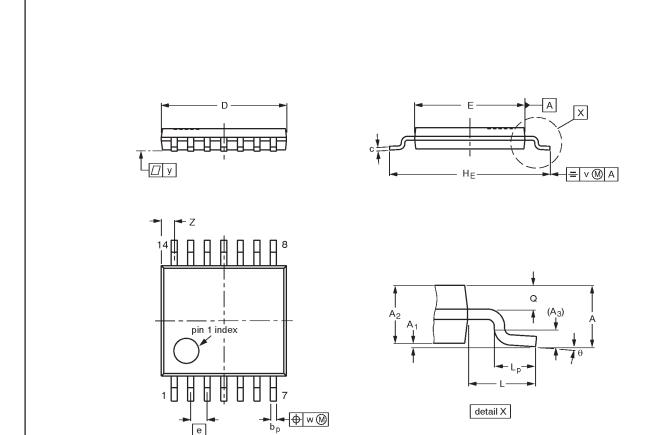
Figure 2. Load circuit for A outputs

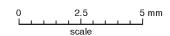
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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	ĺ
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	ĺ
SOT402-1		MO-153			-94-07-12 95-04-04	

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NOTES

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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